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Compensation of transient RF voltage in a double RF system using a kicker cavity



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Outline

- Double RF system

- Motivation
- Physics
- Existing double RF system

- Reduction of Transient beam loading effect

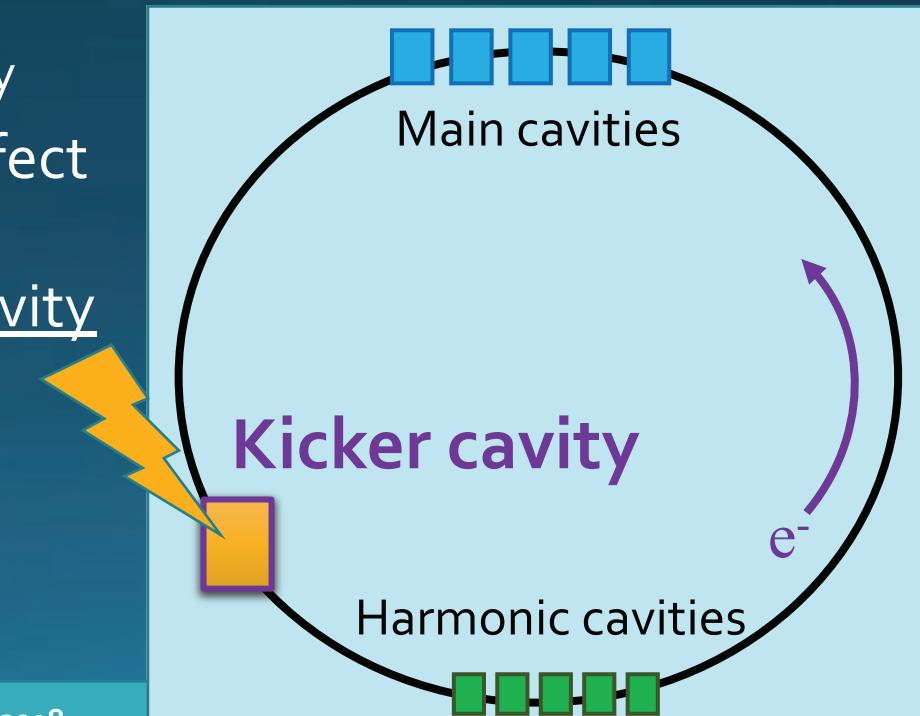
- Transient beam loading effect
- Reduction of the effect
- Normal-conducting TM₀₂₀ cavity

- Compensation of Transient effect

- Basic idea
- Compensation with a kicker cavity
- Numerical estimation

- Summary

*N. Yamamoto, et al., PRAB 21, 012001 (2018).



Motivation for double RF system

- Quasi diffraction-limited synchrotron light sources, which aim at achieving the beam emittances of $\sim < 100$ pmrad are being actively designed.
- In such ultralow-emittance rings, emittance growth due to intrabeam scattering are serious concerns.

<http://kekls.kek.jp>

KEK-LS
parameter

nominal electron energy	E0 [GeV]	3		
circumference	[m]	570.72		
RF frequency	f _{RF} [MHz]	500.07		
harmonic number	h	952		
RF voltage	V _{RF} [MV]	2.5		
energy loss per turn (max. with ID loss)	[MeV]	0.298 (0.851)		
momentum compaction factor	α_c	2.1893x10 ⁻⁴		
damping time x,y,z	[ms]	29.25, 38.28, 22.63		
beam current	[mA]	0	200	500
hor. emittance (not including ID)	[pmrad]	132.51	230.5	314.74
ver. emittance	[pmrad]		8.1	8.2
Touschek lifetime	[h]	—	2.9	1.8
energy spread	$\times 10^{-4}$	6.42	7.24	8.22

Motivation for double RF system

- Quasi diffraction-limited synchrotron light sources, which aim at achieving the beam emittances of $\sim < 100$ pmrad are being actively designed.
- In such ultralow-emittance rings, emittance growth due to intrabeam scattering are serious concerns.

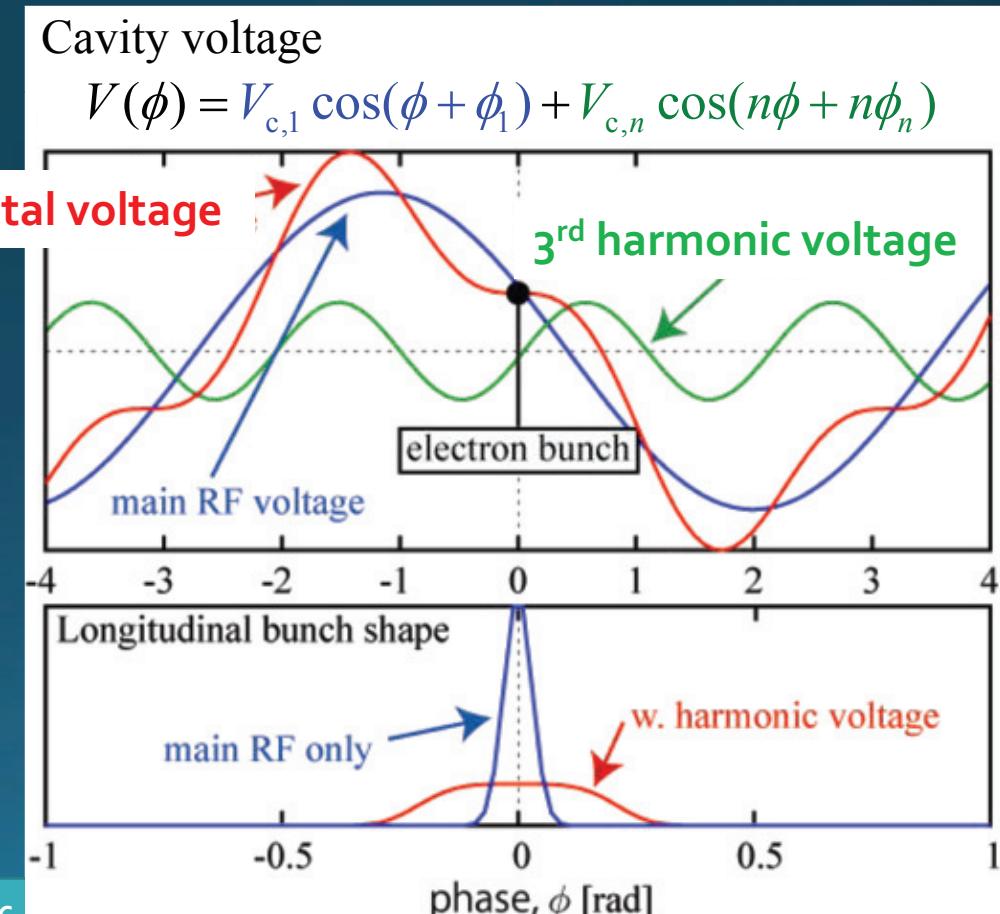
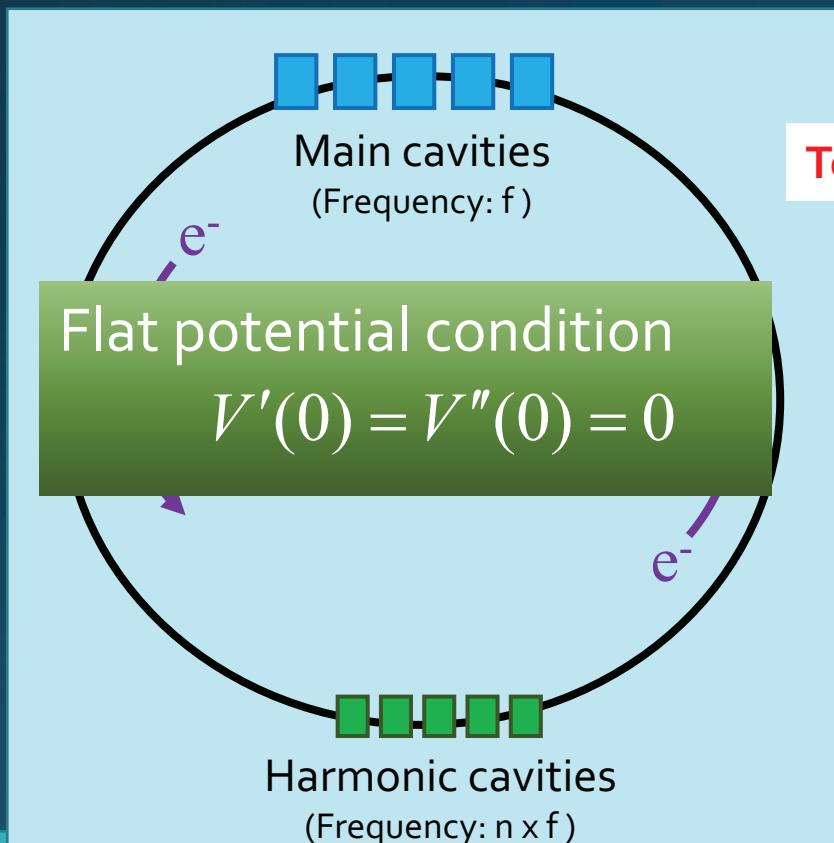
<http://kekls.kek.jp>

KEK-LS parameter	electron energy	E ₀ [GeV]	3		
	RF frequency	f _{RF} [MHz]	500.07		
	RF voltage	V _{RF} [MV]	2.5		
	beam current	[mA]	0	200	500
	hor. emittance	[pmrad]	132.51	230.5	314.74
	Touschek lifetime	[h]	—	2.9	1.8

- One of solutions to mitigate such adverse effects is to reduce the electron densities of the bunches.
- For this purpose, the double RF system is installed.

Physics of double RF system

- Storage ring main cavity is used to replace energy lost through synchrotron radiation.
- By adding n th harmonic voltage (cavity), we can shape the bunch longitudinally.



Physics of double RF system (cont.)

- The bunch shape can be calculated from the total RF voltage.

Total RF voltage

$$V(\phi) = V_{c,1} \cos(\phi + \phi_1) + V_{c,n} \cos(n\phi + n\phi_n)$$

Electron distribution

$$\rho(\phi) = \rho \exp\left(-\frac{1}{\alpha_c^2 \sigma_\varepsilon^2} \Phi(\phi)\right)$$

where

$$\Phi(\phi) = \frac{-\alpha_c}{2\pi h E_0} \int_0^\phi \{e_0 V(\phi') - U_0\} d\phi'$$

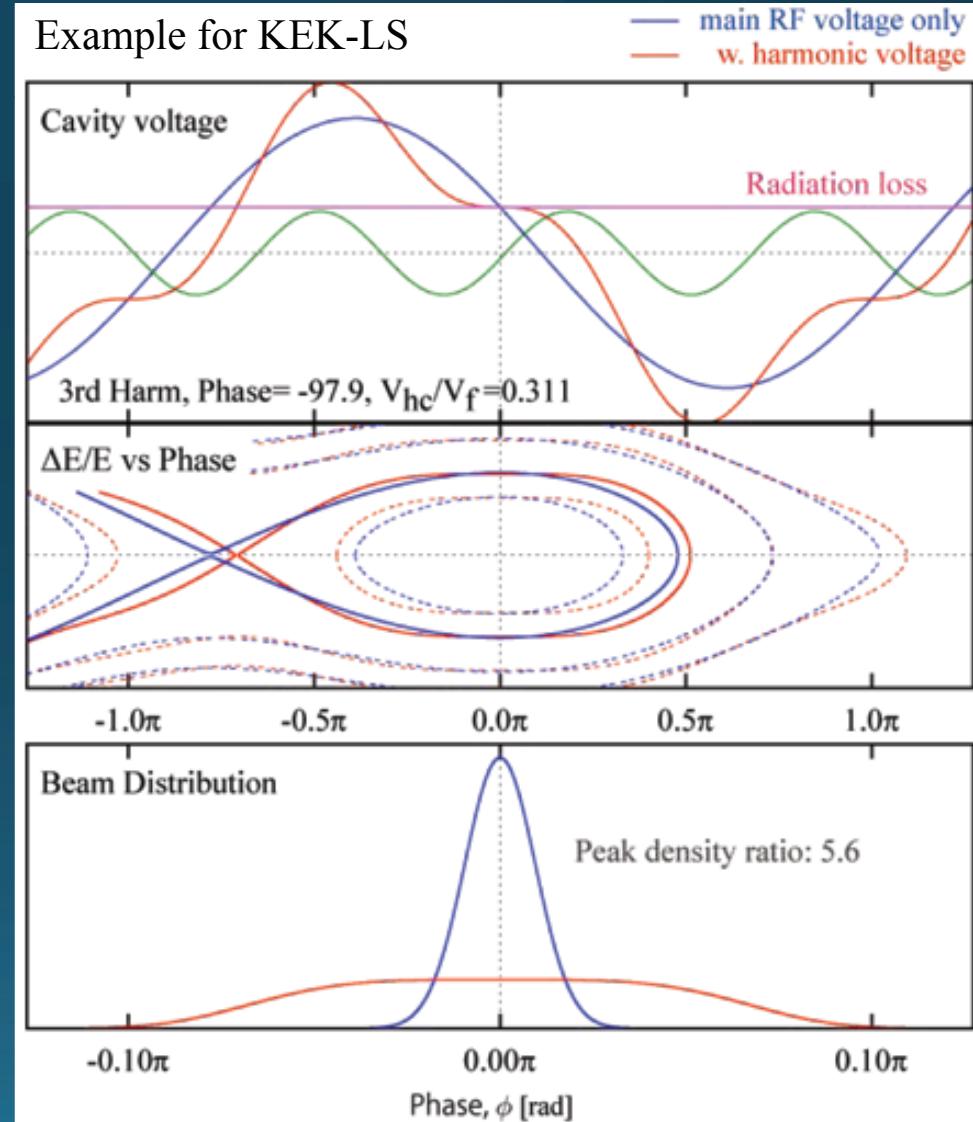
α_c : momentum compaction

h : harmonic number

σ_ε : relative energy spread

E_0 : nominal beam energy

U_0 : turn radiation loss



Existing double RF systems

- Double RF systems have been installed in several 3rd generation light sources, and they have been successfully operated to lengthen beam bunches. (ALS, BESSY-II, SLS, ELETTRA, MAX-IV, ...)

- [1] J. M. Byrd, et al., Nucl. Instrum. Methods Phys. Res., Sect. A 455, 271 (2000).
- [2] M. Georgsson, et al., Nucl. Instrum. Methods Phys. Res., Sect. A 469, 373 (2001).
- [3] W. Anders and P. Kuske, in Proceedings of PAC 2003, (2003) p. 1186.
- [4] M. Pedrozzi, et al., in Proceedings of SRFo3 (2003) p. 91
- [5] G. Penco and M. Svandrlík, Phys. Rev. Accel. Beams 9, 044401 (2006).
- [6] N. Milas and L. Stingelin, in Proceedings of IPAC'10 (2010) p. 4719.
- [7] P. F. Tavares, et al., Phys. Rev. Accel. Beams 17, 064401 (2014).

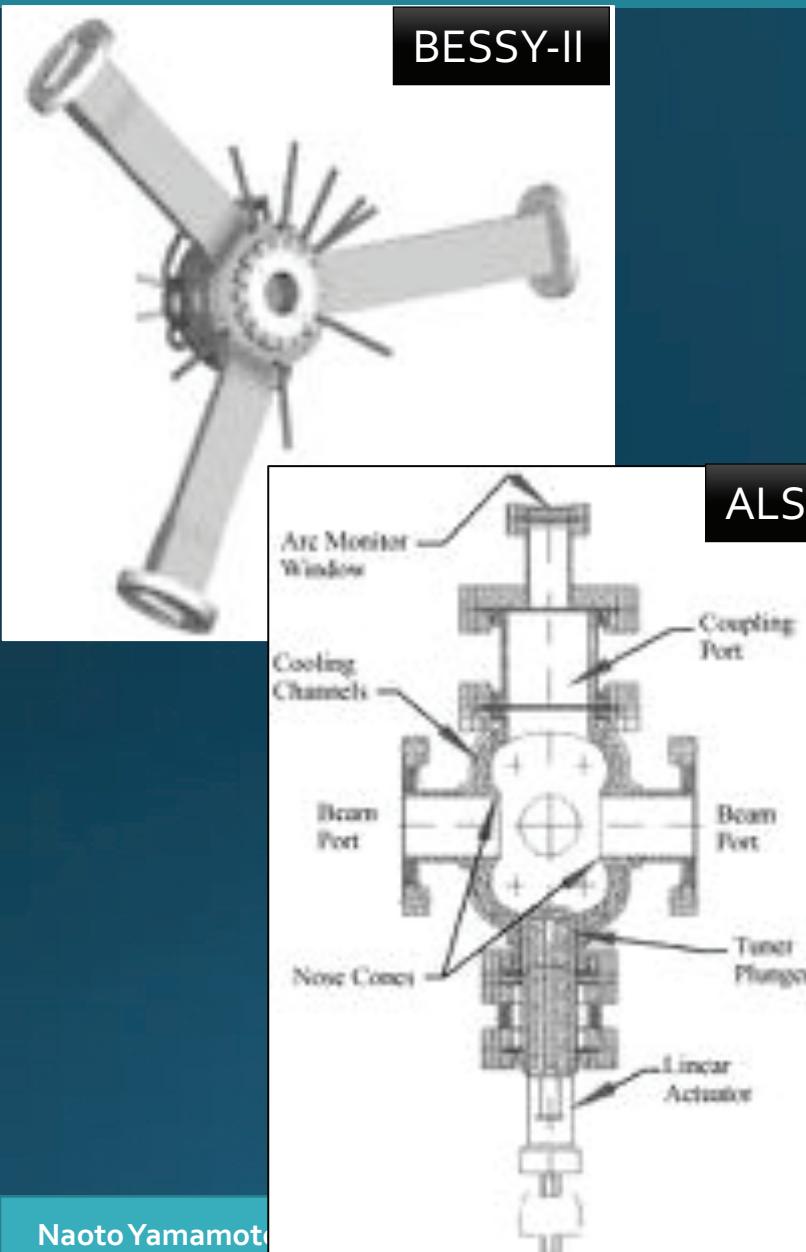
- Existing 1.5GHz harmonic cavity (3rd harm. of 500MHz main cavity)

	BESSY-II	ALS	SLS/ELETTRA
NC or SC	NC	NC	SC
R/Q	Ω	124	161
Unloaded-Q (Q_0)	13,900	21,000	2.0E+08
Shunt impedance (R) $M\Omega$	1.72	3.38	35200

$$R \equiv V_c^2 / P_c$$

*NC: Normal conducting
SC: Super conducting

Existing harmonic cavities (cont.)



	BESSY-II	ALS	SLS/ELETTRA
Type	NC	NC	SC
R/Q	Ω	124	161
Q_0		13,900	21,000
R	M Ω	1.72	3.38
			35200

Bessy-II : W.Anders, et .al., Proc. PAC (2003) TPAB004

ALS : J. Byrd, et. al., NIM A, 439 (2000) pp.15-25

SLS: N. Milas. et.al., Proc. IPAC'10 (2010) THPE084

Outline

- Double RF system
 - Motivation
 - Physics
 - Existing double RF system
- Reduction of Transient beam loading effect
 - Transient beam loading effect
 - Reduction of the effect
 - Normal-conducting TM₀₂₀ cavity
- Compensation of Transient beam loading effect
 - Basic idea
 - Compensation with a kicker cavity
 - Numerical estimation
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Transient beam loading effect

- When the gaps (i.e. unoccupied RF buckets) are introduced in the fill pattern of the stored beam, the bunch gaps induce considerable variations in both amplitude and phase in the RF voltage.
- The higher frequency ($> 1.5\text{GHz}$) cavity, the effect is more serious.

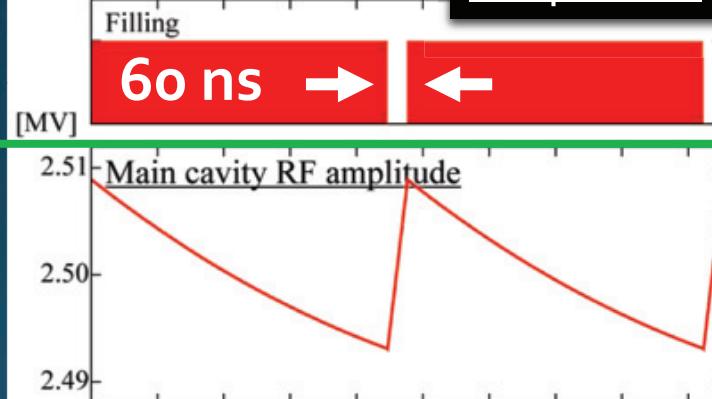
Cavity voltage vs Bucket index

(60 ns gap,
KEK-LS)

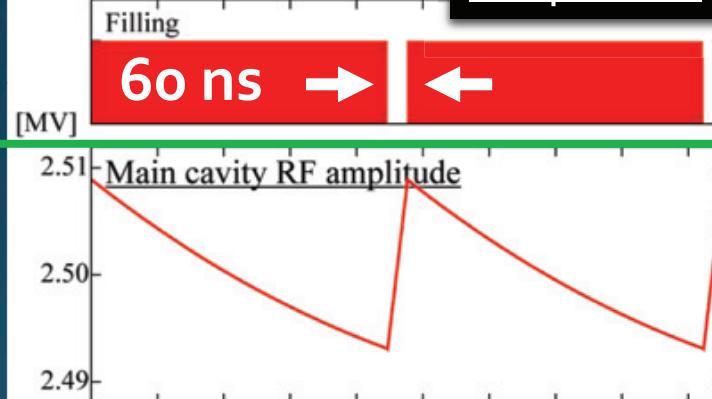
Main cavity
(500MHz)

$$|\Delta \tilde{V}_c| / |\tilde{V}_c| = 1.6 \%$$

Amplitude

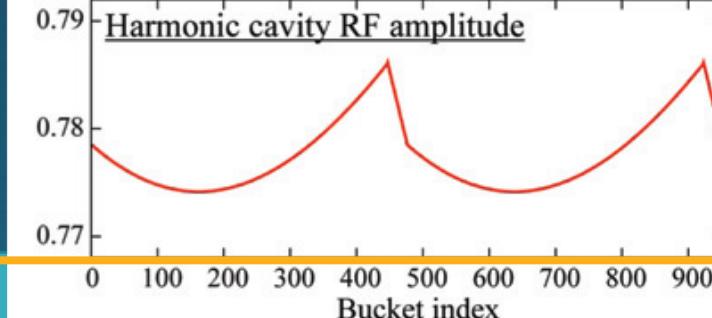
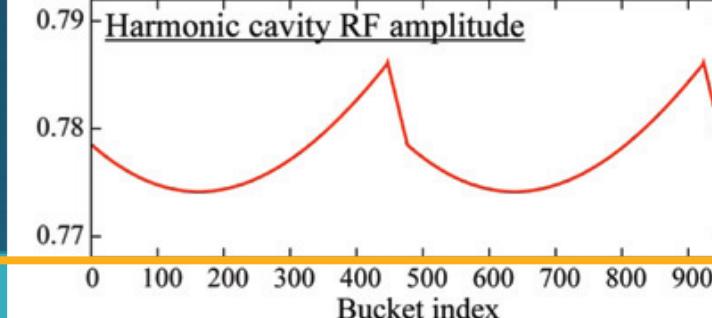


Phase



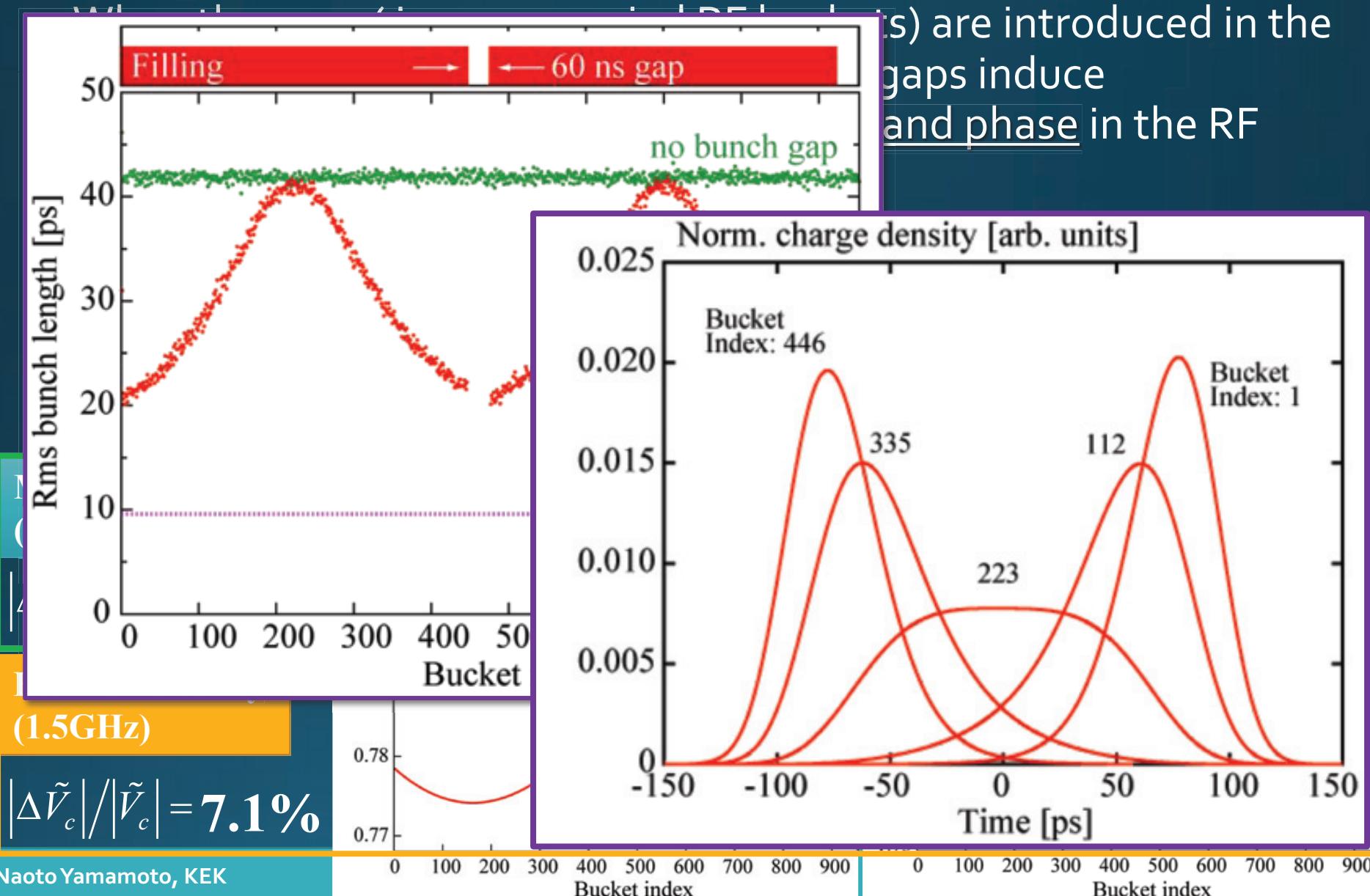
Harmonic cavity
(1.5GHz)

$$|\Delta \tilde{V}_c| / |\tilde{V}_c| = 7.1 \%$$



Transient beam loading effect

60 ns gaps are introduced in the filling sequence. These gaps induce transient beam loading effect and phase in the RF.

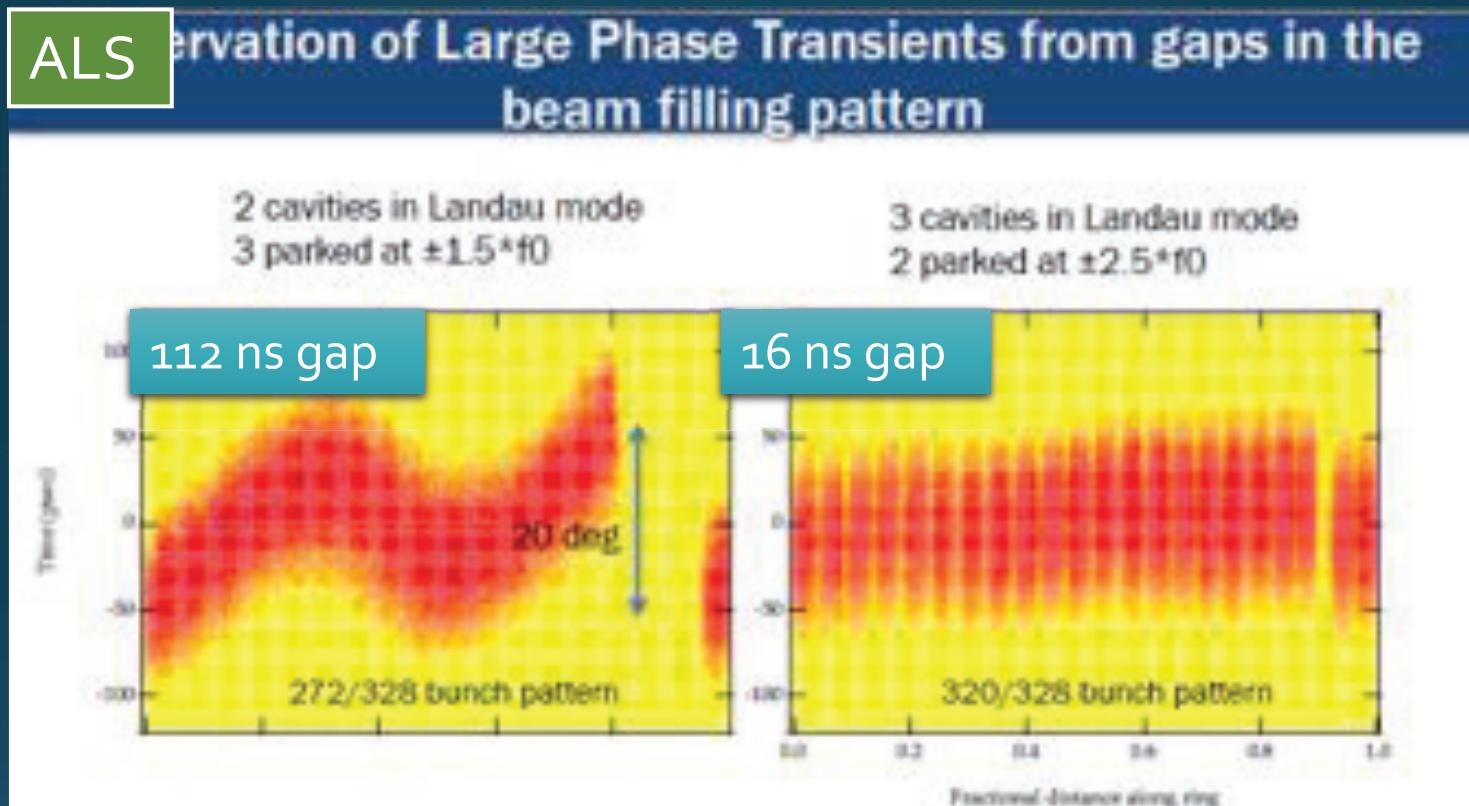


Transient beam loading effect (cont.)

- NC harmonic cavity

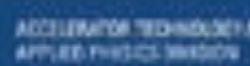
*J. Byrd's presentation on ALERT, Sep. 2016

*J. M. Byrd, et al., NIMA 455, 271 (2000).



Unequal fill or gap of 20-25% (users' demand) aggravates this problem.

This result was NOT expected and not reported in prior literature.
We began an investigation to understand the effect.



Transient beam

SLS

*M. Pedrozzi, et al., SRFo3 (2003) p. 91

- SC harmonic cavity

better than NC-cavity,
but the considerable effect.

*G. Penco and M. Svandrlik,
PRAB 9, 044401 (2006).

ELETTRA

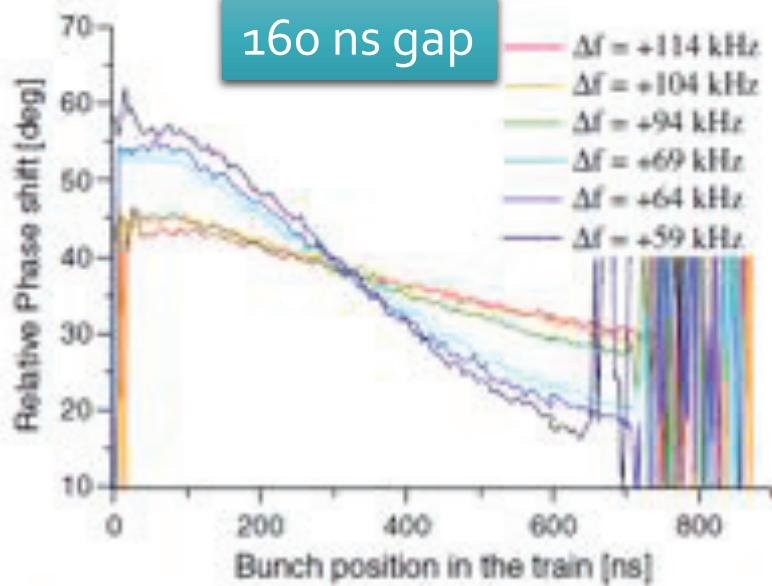


FIG. 6. (Color) Relative stable phase along the bunch train vs the SHC detuning, for a 80% filling; $I_{beam} = 315 \text{ mA}$, $E = 2.0 \text{ GeV}$.

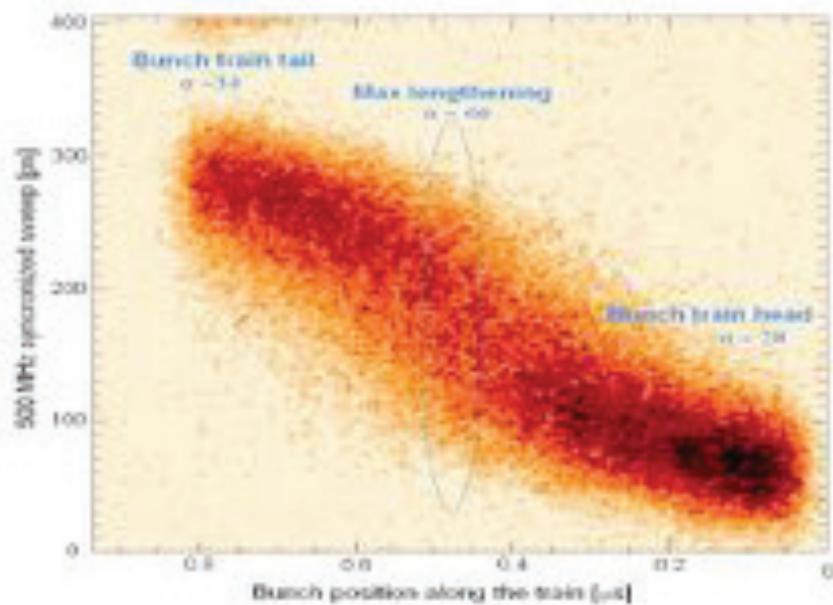
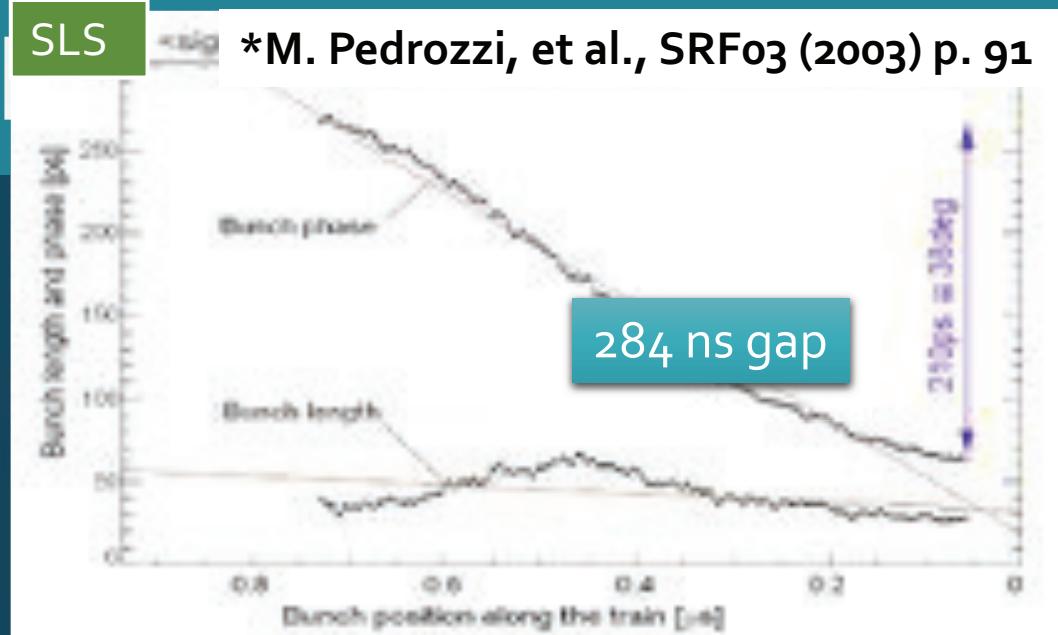
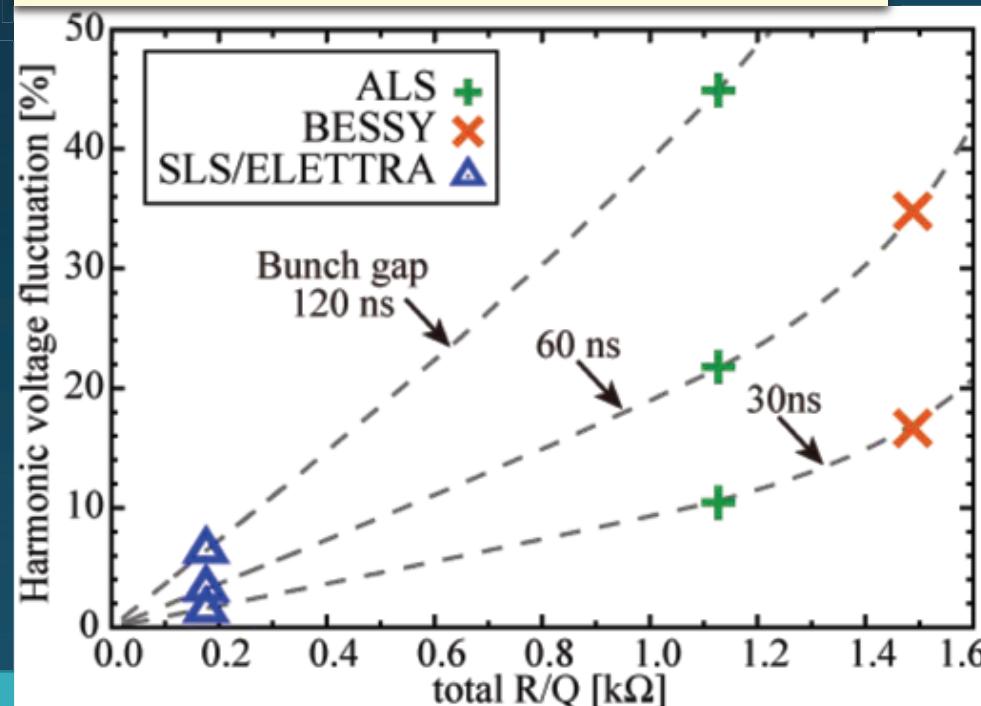


Figure 4: Streak camera snapshot at 320mA. Bunch σ and phase in ps versus position in the bunch train.

Reduction of the effect

- Such transient effects were well-investigated by J. Byrd, et al. .
- It was reported that the reduction of a total R/Q of harmonic cavities is essential to alleviate such transient effects.

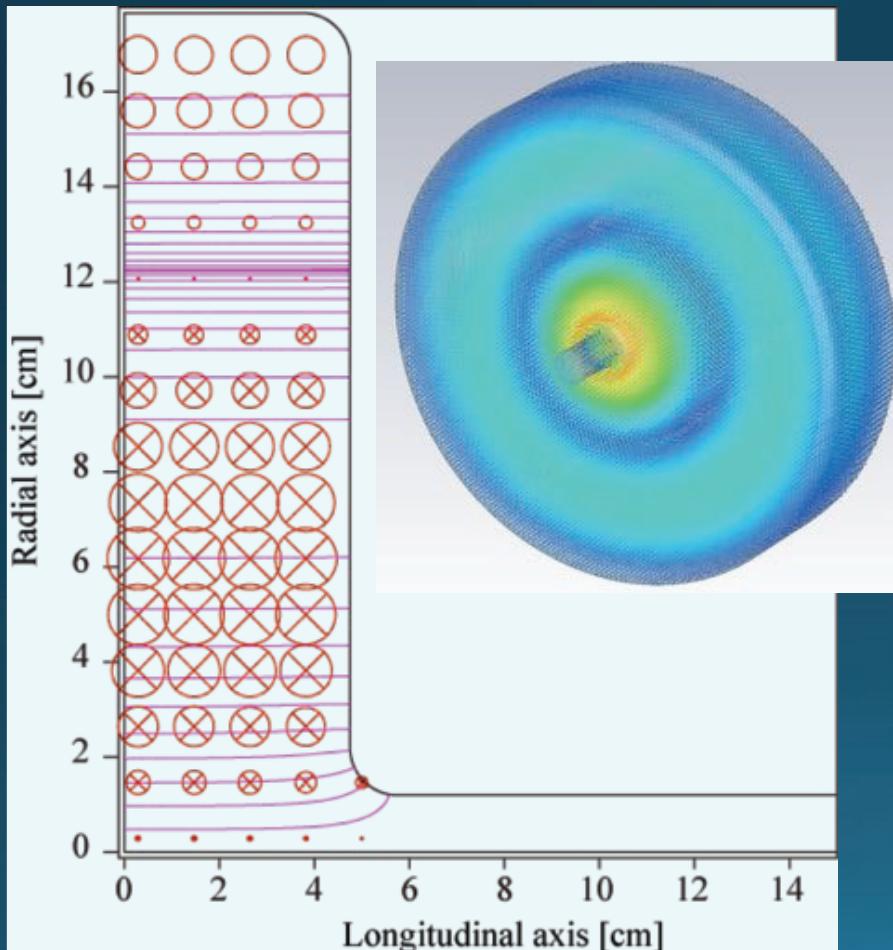
Harmonic voltage fluctuation (KEK-LS) vs Total R/Q



		BESSY-II	ALS	SLS/ ELETTRA
R/Q	Ω	124	161	176
Unloaded-Q		13900	21000	$2.0\text{E}+08$
Coupling	β	0.82	1.08	3099
Loaded- Q		7631	10088	64514
Fill time	us	1.6	2.1	13.7
Cav. number		12	7	1
total R/Q	Ω	1488	1127	176
V_{hc} / cav.	kV	65	111	777
P_c / cav.	kW	2.4	3.6	0.0
$\Delta V_c/V_c(60ns)$		35.0%	22.0%	3.2%

Normal-conducting harmonic TM₀₂₀ cavity

- Normal conducting TM₀₂₀ cavity is a candidate because of its high unloaded-Q and small R/Q (large stored energy).



Parameter	Symbol	Value
Resonant frequency	f_{res}	1.5 GHz
R/Q	R/Q	77.2Ω
Unloaded Q	Q_0	37500
Inner radius	-	176.5 mm
Gap length	-	95 mm
Max. power dissipated on the cavity wall		
	$P_{c,max}$	10 kW
Cavity voltage at $P_{c,max}$	$V_{c,cell}$	170 kV
Max. electric field on the inner surface		
	E_{max}	3.2 MV/m
Max. power density on the inner surface		
	ρ_{max}	10 W/cm ²

HOM-Damped TM₀₂₀ cavity (508MHz)

* H. Ego, et. al., PASJ11, (2014) MOOL14

- This type cavity was pioneered by Dr. Ego and was developed as a accelerating cavity for the “Spring-8 II” storage ring.

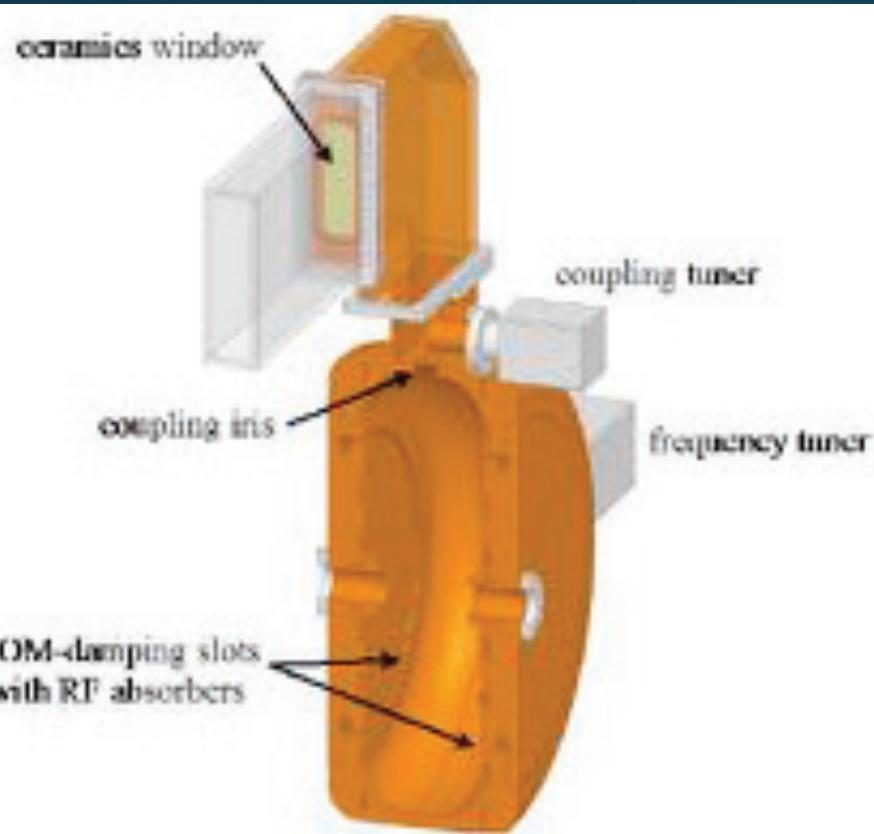


Figure 1: Structure of the new HOM-damped cavity.

Table 1: RF Properties of the TM₀₂₀ Mode

Shunt impedance (R_a) [MΩ]	6.8
Unloaded Q (Q_a)	60,300
R_a/Q_a	113
Accelerating voltage [kV]	900

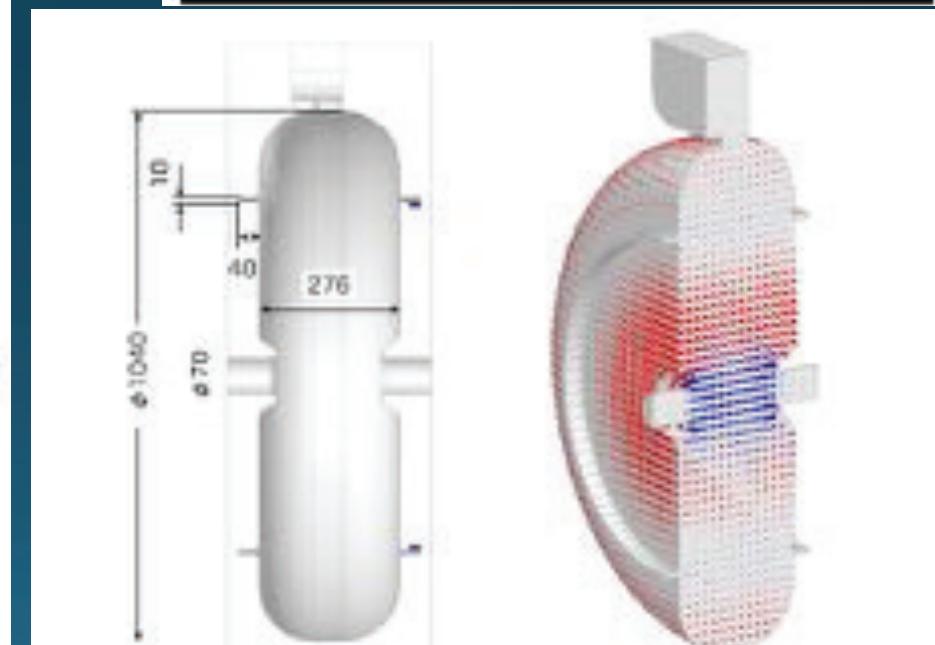


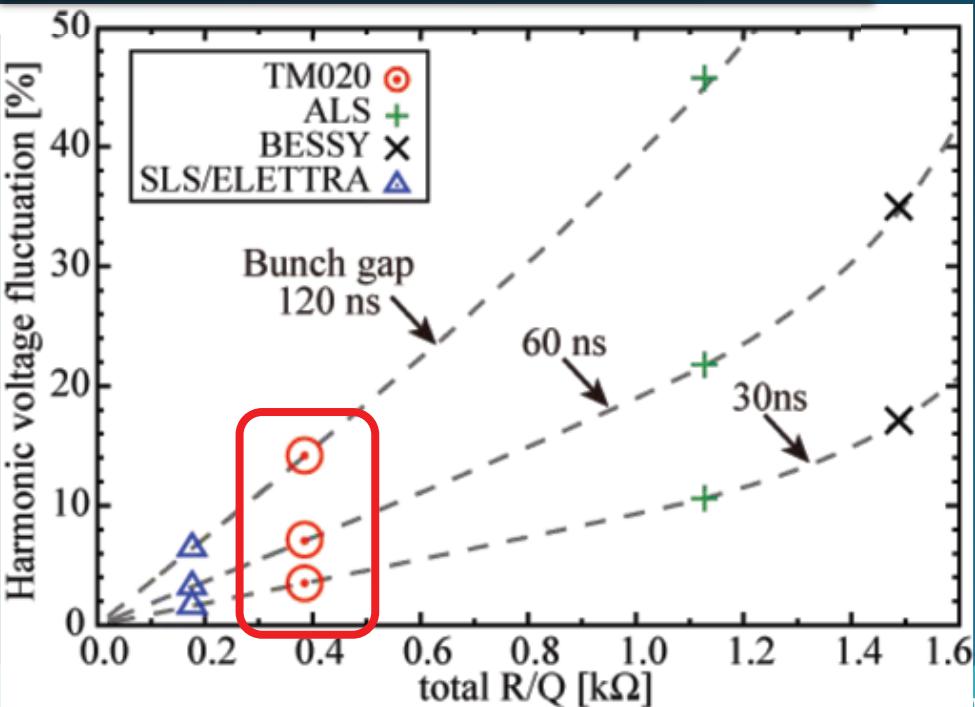
Figure 3: Inner shape of the cavity and the TM₀₂₀ field distributions. Blue and red arrows show electric and magnetic fields, respectively.

Normal-conducting TM₀₂₀ cavity

*N. Yamamoto, et al., PRAB 21, 012001 (2018).

- Normal conducting TM₀₂₀ cavity is a candidate because of its high unloaded-Q and small R/Q (large stored energy).

Harmonic voltage fluctuation (KEK-LS) vs Total R/Q

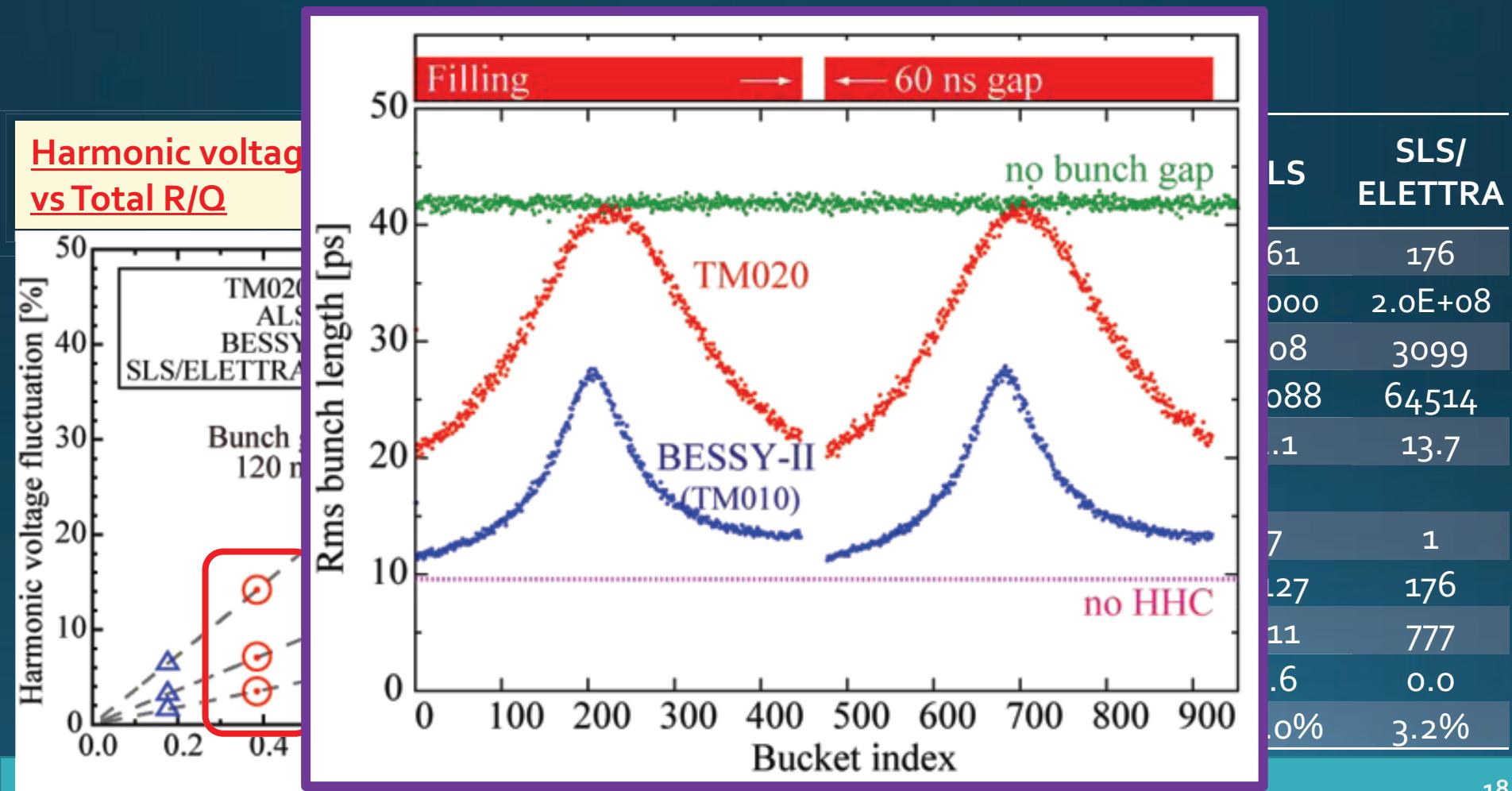


	TM ₀₂₀	ALS	SLS/ ELETTRA	
R/Q	Ω	77	161	176
Unloaded-Q		37449	21000	2.0E+08
Coupling	β	0.27	1.08	3099
Loaded-Q		29411	10088	64514
Fill time	us	6.2	2.1	13.7
Cav. number		5	7	1
total R/Q	Ω	385	1127	176
V _{hc} / cav.	kV	155	111	777
P _c / cav.	kW	8.4	3.6	0.0
ΔV _c /V _c (6ons)		7.1%	22.0%	3.2%

Normal-conducting TM₀₂₀ cavity

*N. Yamamoto, et al., PRAB 21, 012001 (2018).

- Normal conducting TM₀₂₀ cavity is a candidates because of it's high unloaded-Q and small R/Q (large stored energy).



Outline

- Double RF system
 - Motivation
 - Physics
 - Reviews of existing double RF system
- Reduction of Transient beam loading effect
 - Transient beam loading effect
 - Key parameter for the reduction of the effect
 - Normal-conducting TM₀₂₀ cavity
- Compensation of Transient beam loading effect
 - Basic idea
 - Compensation with a kicker cavity
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Basic idea of the compensation

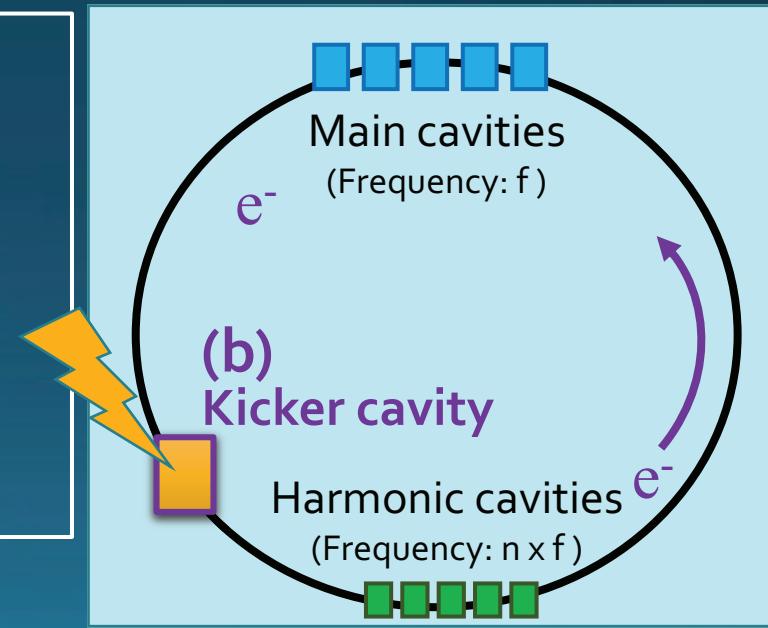
- If the voltage fluctuation is small, we can further reduce the transient effect using an active compensation technique.
- We have investigated two measures;
 - (a) compensation on the main and harmonic cavities,
 - (b) compensation using a separate kicker cavity.**

Advantage of the method (b)

- Input RF power is minimized by optimizing the cavity bandwidth.

Disadvantage

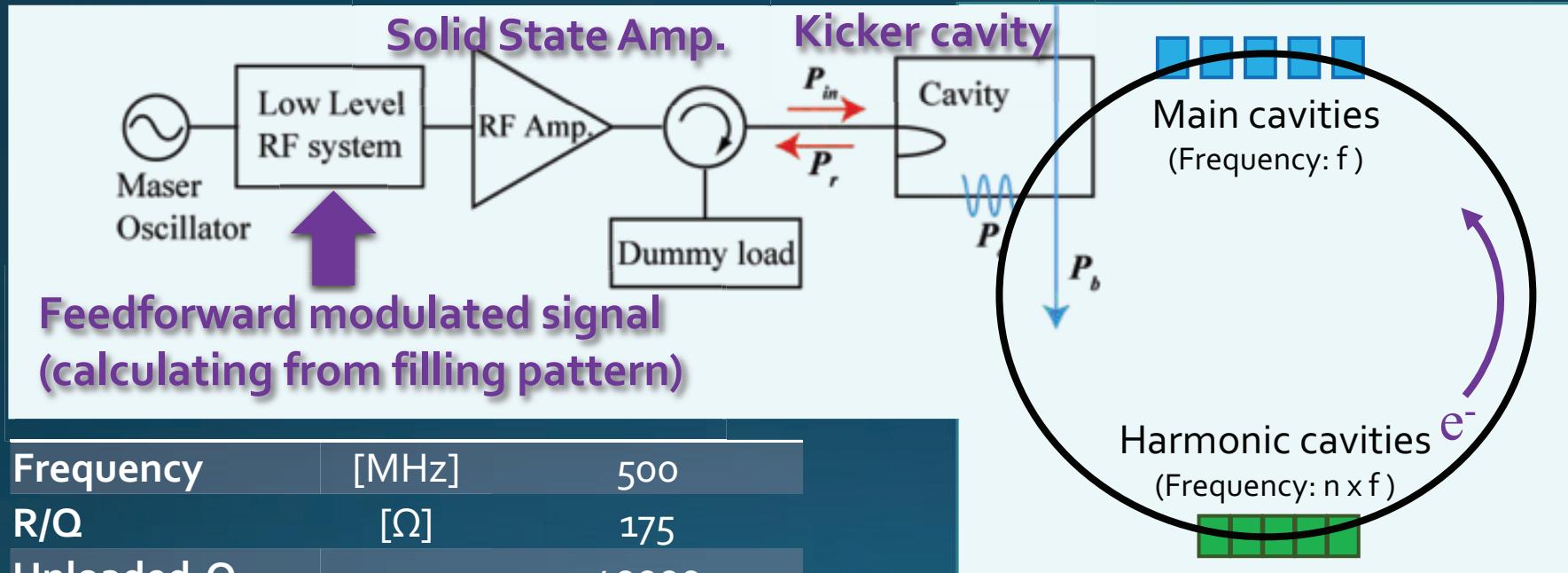
- Another space in the ring, RF system (low level system, RF amp ...)



Compensation with a kicker cavity

System overview

We consider to use an active feedforward low level control, a kicker cavity having the wide bandwidth and a Solid state amplifier.



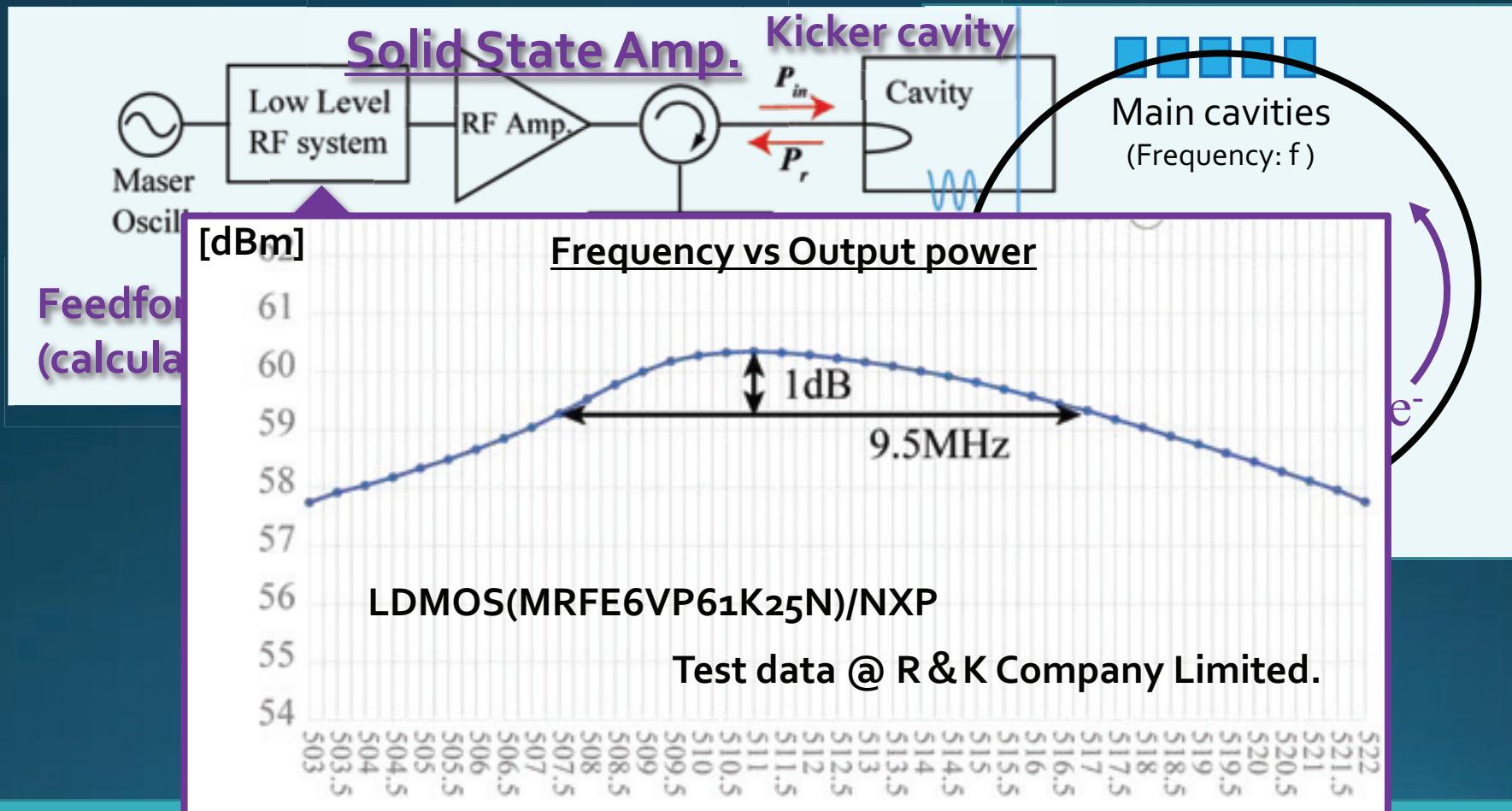
Frequency	[MHz]	500
R/Q	[Ω]	175
Unloaded-Q		40000
Cavity number		1
Cavity coupling		199
Loaded-Q		200
3dB bandwidth	[MHz]	2.5

← assumed kicker cavity parameters
(not optimized)

Compensation with a kicker cavity

System overview

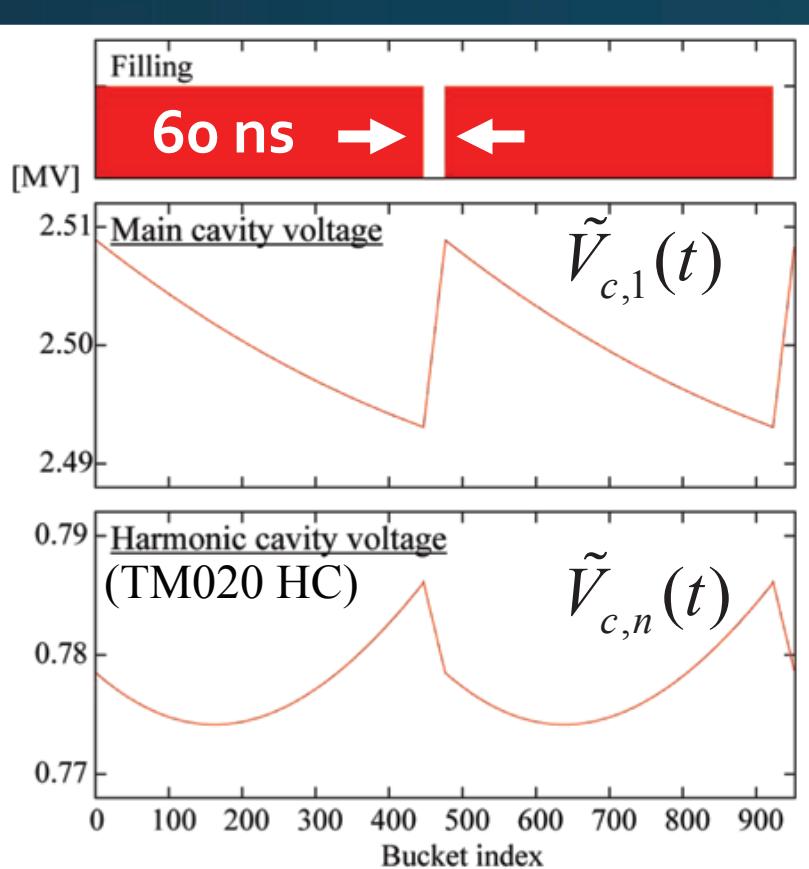
We consider to use an active feedforward low level control, a kicker cavity having the wide bandwidth and a Solid state amplifier.



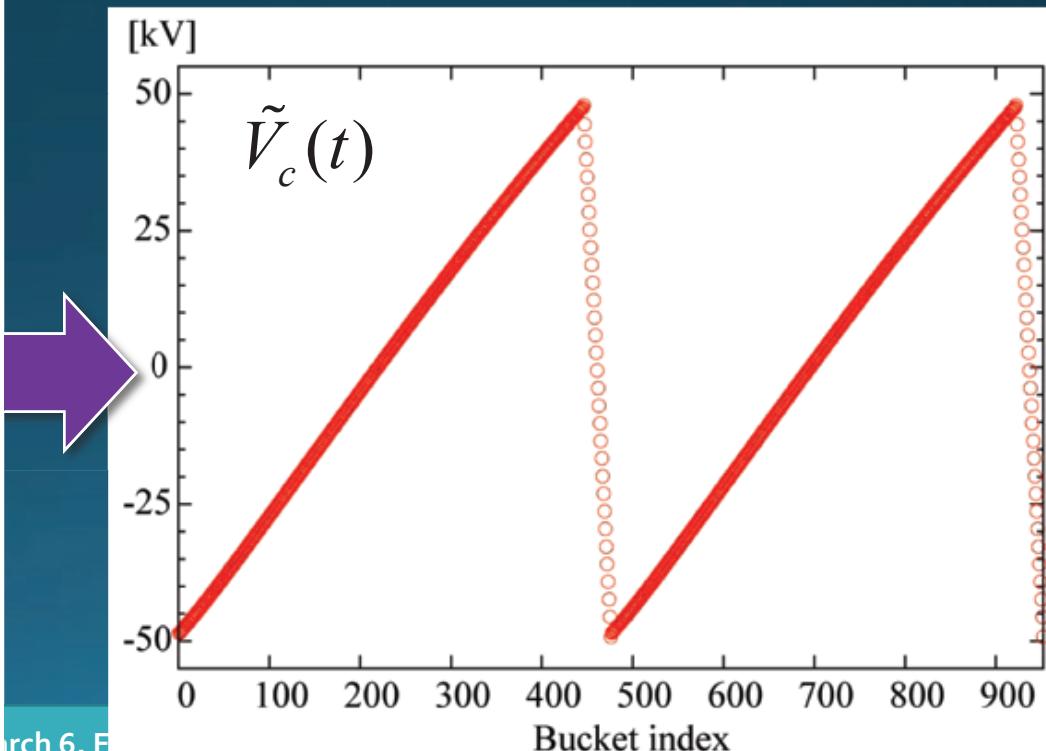
Numerical estimation (KEK-LS)

How to obtain the feedforward signal

1. The RF voltage of the kicker cavity can be decided to suppress phase shifts of the bunches along the train.
 - * Main and harmonic voltage can be evaluated from the fill pattern.



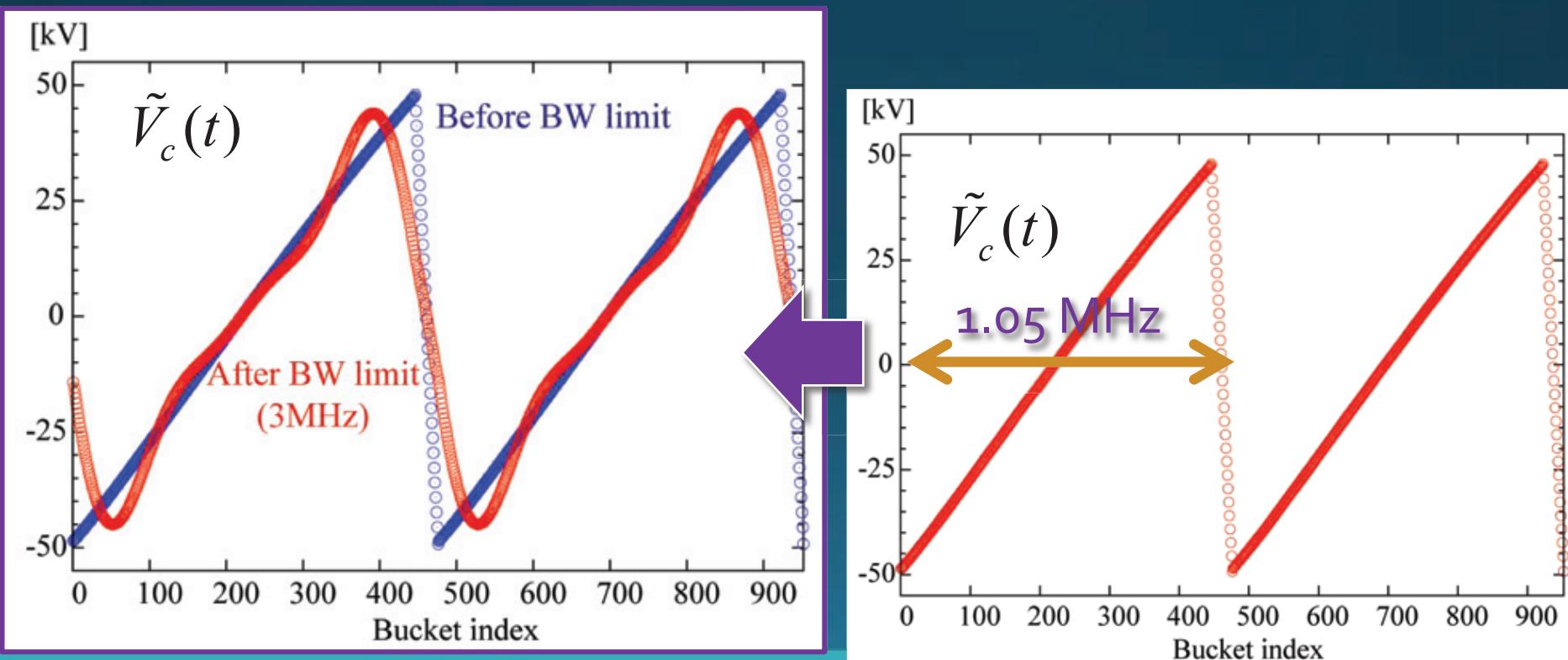
$$\tilde{V}_c(t) = -\left(\text{Re} \left[\tilde{V}_{c,1}(t) + \tilde{V}_{c,n}(t) \right] - U_0 \right)$$



Numerical estimation (KEK-LS)

How to obtain the feedforward signal

1. Evaluate the kicker cavity voltage
2. Apply the bandwidth limitation, where the bandwidth should be wider than the repetition frequency of the bunch train.



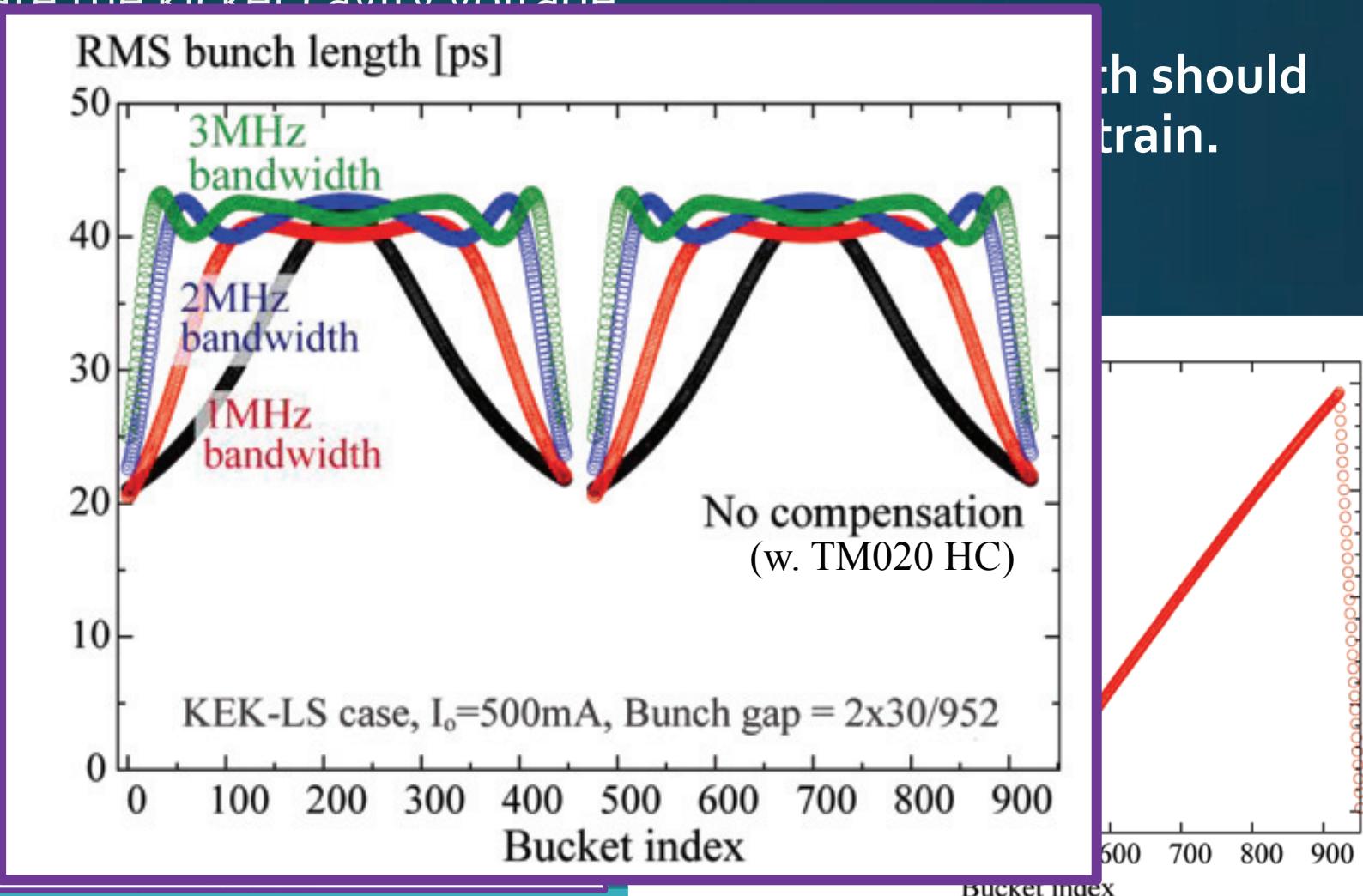
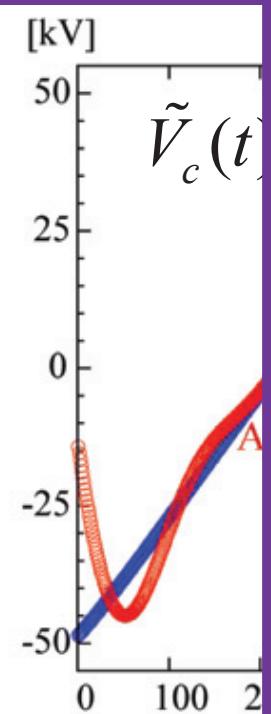
Numerical estimation (KEK-LS)

How to obtain the feedforward signal

1. Evaluate the kicker cavity voltage

2. Apply
be wide

width should
train.



Numerical estimation (KEK-LS)

How to obtain the feedforward signal

1. Evaluate the kicker cavity voltage
2. Apply the bandwidth limitation, considering the repetition frequency of the bunch train.

※ Input RF power can be estimated, taking into account the cavity and amplifier responses.

$$\tilde{V}_g(t) = (\tilde{V}_c(t))_{\text{target}} - \tilde{V}_b(t)$$

$$k \tilde{i}_g(t) = \frac{d\tilde{V}_g(t)}{dt} + \frac{1}{\tau_f} \tilde{V}_g(t)$$

$$\tilde{V}_g^{\text{limit}}(t) = \left[\tilde{V}_g^{\text{limit}}(-\infty) + k \int_{-\infty}^t \tilde{i}_g(t') e^{-t'/\tau_f} dt' \right] \cdot e^{\alpha/\tau_f t}, P_g(t) = \frac{R}{16\beta} |\tilde{i}_g^{\text{limit}}(t)|^2$$

*N. Yamamoto, et al., PRAB 21, 012001 (2018).

skip

\tilde{i}_g : generator current of kicker cavity

k : loss parameter of kicker cavity

R : shunt impedance of kicker cavity

β : cavity coupling coefficient

Numerical estimation (KEK-LS)

How to obtain the feedforward signal

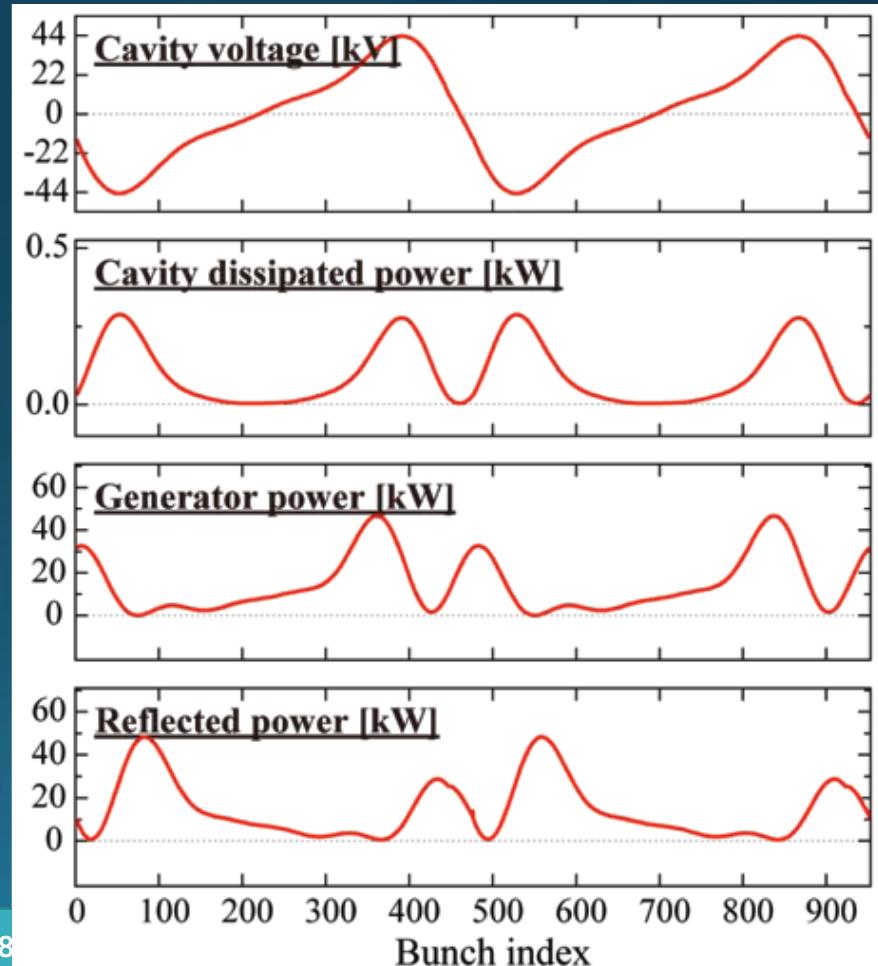
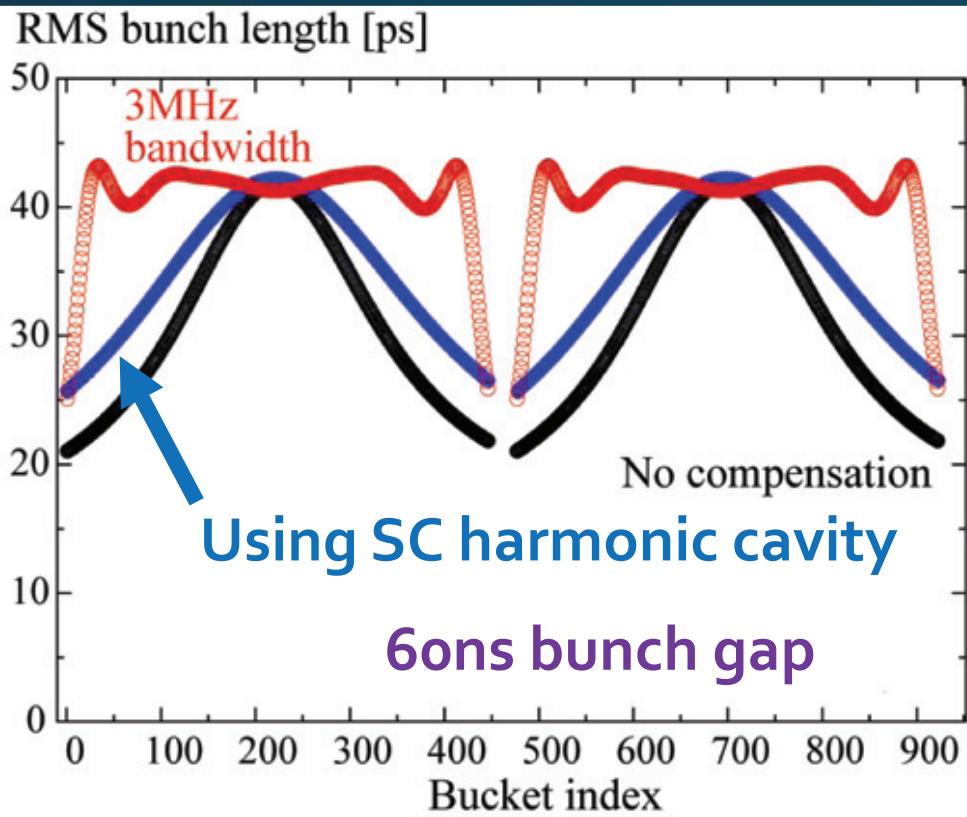
1. Evaluate the kicker cavity voltage
2. Apply the bandwidth limitation, considering the repetition frequency of the bunch train.

※ Input RF power can be estimated, taking into account the cavity and amplifier responses.

Compensation bandwidth [MHz]	Average Bunch length [ps]	Peak Generator Power [kW]	Average Generator Power [kW]
—	31.1	—	—
1	35.6	11.1	5.6
2	39.6	31.6	11.1
3	40.9	46.7	14.7

Numerical estimation (KEK-LS)

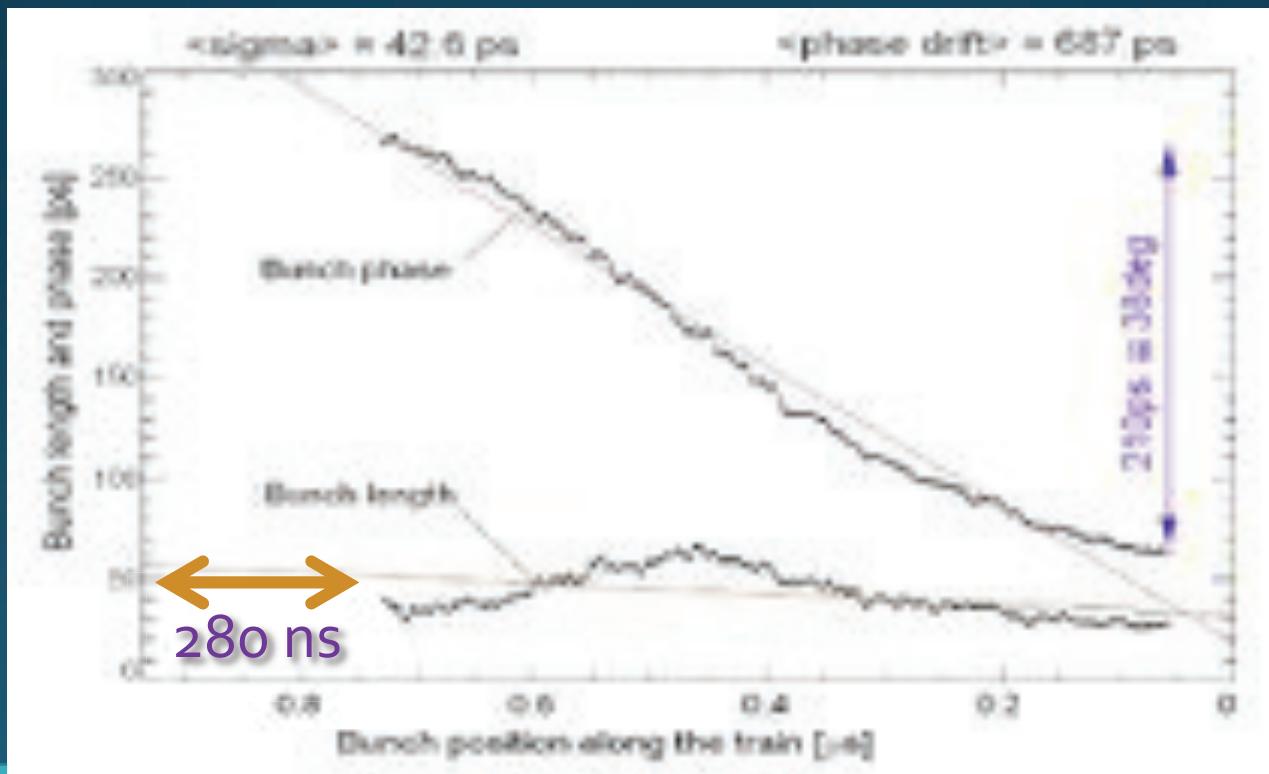
Compensation bandwidth [MHz]	Average Bunch length [ps]	Peak Generator Power [kW]	Average Generator Power [kW]
3	40.9	46.7	14.7



Numerical estimation (SLS)

- Such compensation scheme can be applied to the SC harmonic system.
- At SLS, when the bunch gap was around 280 ns, considerable transient effect was observed.

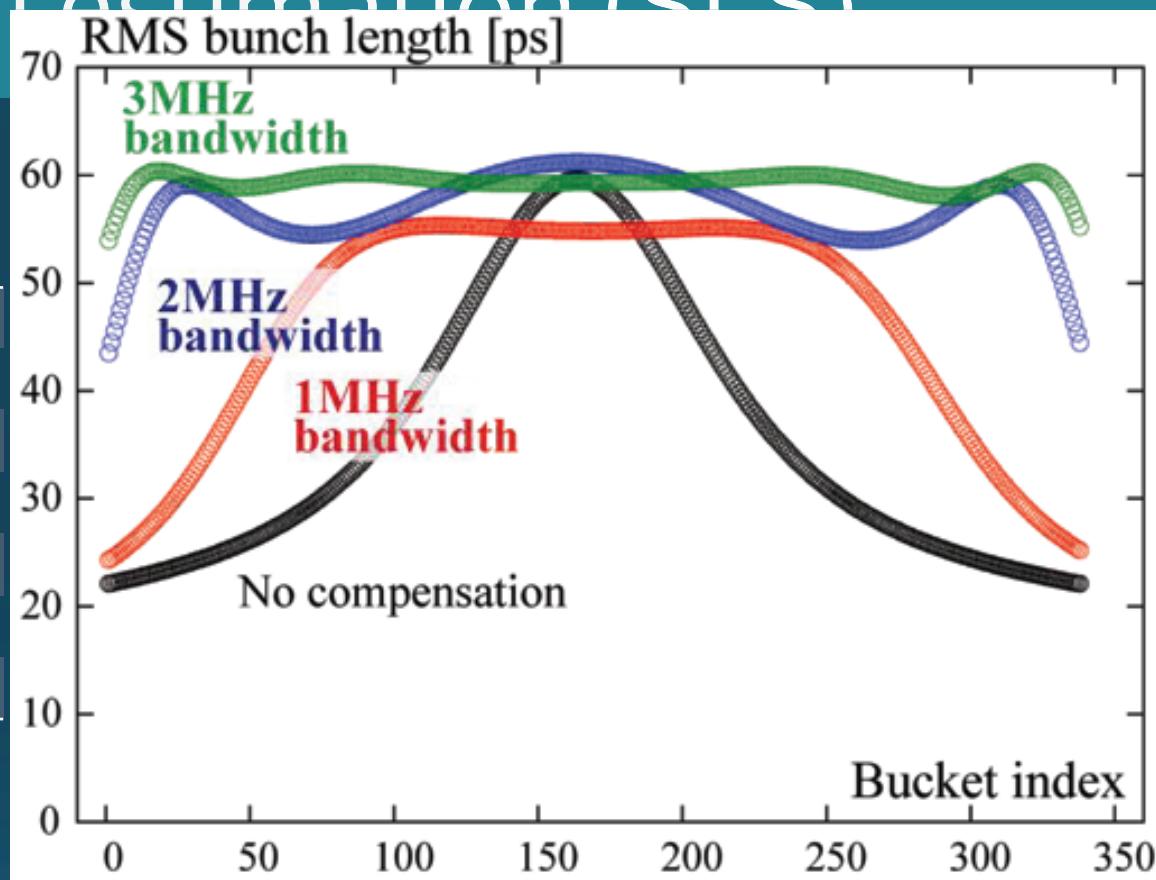
*M. Pedrozzi, et al., SRF03 (2003) p. 91



Numerical Estimation (SLS)

Kicker cavity parameter
(not optimized)

Frequency	[MHz]	500
R/Q	[Ω]	175
Unloaded-Q		40000
Cavity number		1
Cavity coupling		199
Loaded-Q		200
3dB bandwidth	[MHz]	2.5



Compensation bandwidth [MHz]	Average Bunch length [ps]	Peak Generator Power [kW]	Average Generator Power [kW]
—	35.8	—	—
1	46.3	25.8	16.8
2	56.9	84.1	35.6
3	59.3	98.3	39.1

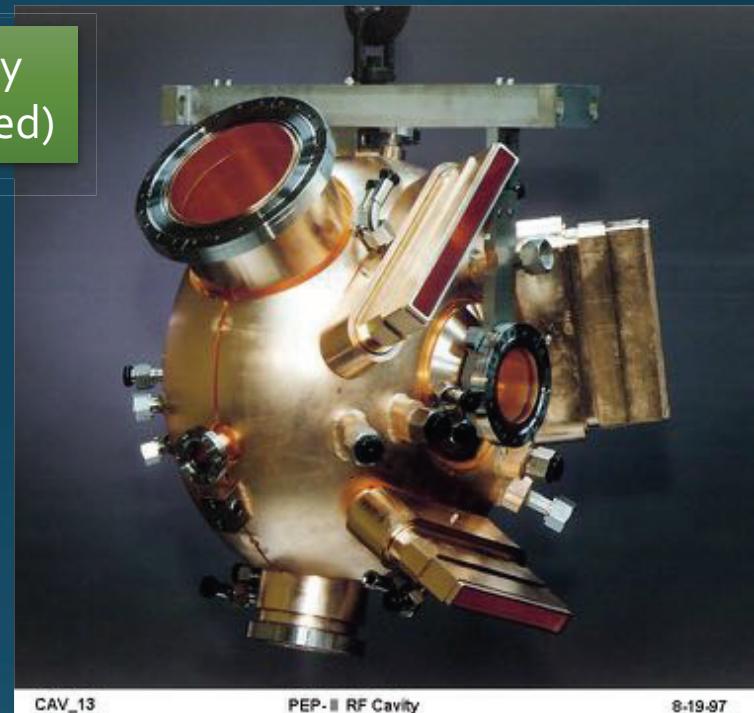
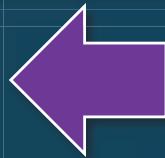
Numerical estimation (SLS)

* R.A. Rimmer, LBL-33360, UC-414 (1992); and related papers.

Kicker cavity parameter (not optimized)

Frequency	[MHz]	500
R/Q	[Ω]	230
Unloaded-Q		30000
Cavity number		1
Cavity coupling		149
Loaded-Q		200
3dB bandwidth	[MHz]	2.5

PEP-II cavity
(HOM-damped)



8-19-97

Compensation bandwidth [MHz]	Average Bunch length [ps]	Peak Generator Power [kW]	Average Generator Power [kW]
—	35.8	—	—
3	59.3	98.3 -> 81.5	39.1-> 31.6

Summary

- Double RF system is essential in ring based future light source.
- Normal conducting TM₀₂₀ cavity is a candidates for harmonic cavities because of it's high unloaded-Q and small R/Q (large stored energy).
- By using single kicker cavity with active feedforward LLRF system, the beam loading effect for the double RF system can be minimized and avoided.
(This technique can be applied to not only NC but also SC systems.)

Future tasks

- Concrete designs of
 - the HOM-damped/high-coupling kicker cavity
 - the (adaptive) feedforward Low level RF system
 - Several tens kW level solid state amp. with wide bandwidth.